

HVM17

Variable Capacitance Diode for FM tuner

HITACHI

Preliminary
Rev. 2
May. 1993

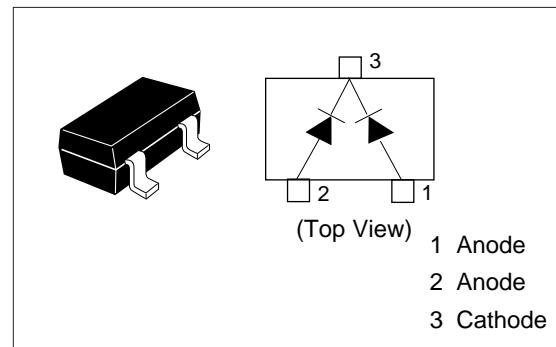
Features

- Good linearity of C-V curve.
- To be usable at low voltage.
- High figure of merit. (Q=50 min)
- MPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HVM17	T 6	MPAK

Pin Arrangement



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Reverse voltage	V_R	15	V
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse voltage	V_R	15	—	—	V	$I_R = 10 \mu\text{A}$
Reverse current	I_R	—	—	100	nA	$V_R = 9 \text{ V}$
Capacitance	C_1	50.0	—	85.0	pF	$V_R = 1 \text{ V}$, $f = 1 \text{ MHz}$
	C_3	16.1	—	27.3	pF	$V_R = 3 \text{ V}$, $f = 1 \text{ MHz}$
	$C_{4.5}$	5.23	—	8.84	pF	$V_R = 4.5 \text{ V}$, $f = 1 \text{ MHz}$
Capacitance ratio	n	5.6	—	—	—	$C_1/C_{4.5}$
Figure of merit	Q	50	—	—	—	$V_R = 2.5 \text{ V}$, $f = 10 \text{ MHz}$
ESD-Capability	—	80	—	—	V	* $C = 200 \text{ pF}$, Both forward and reverse direction 1 pulse.

* Failure criterion ; $I_R \geq 100 \text{ nA}$ at $V_R = 9 \text{ V}$

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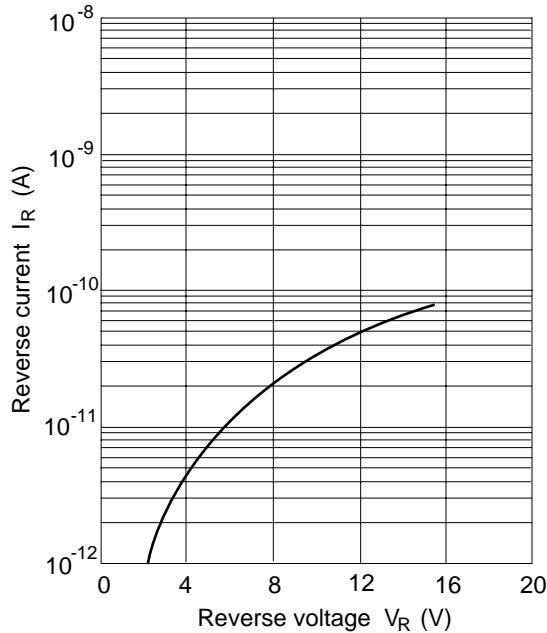


Fig.1 Reverse current Vs.
Reverse voltage

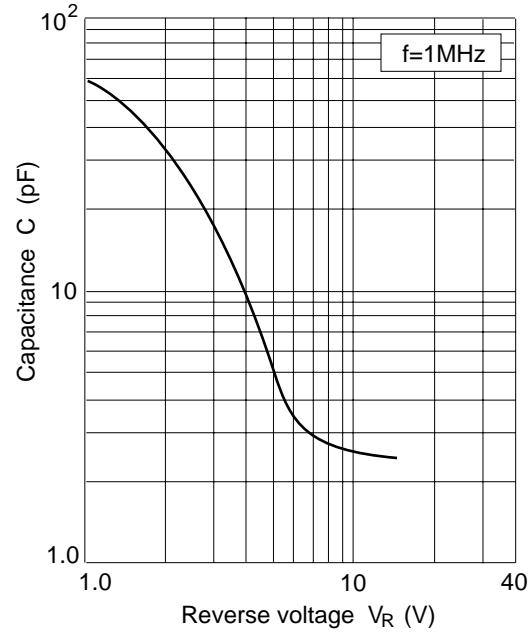


Fig.2 Capacitance Vs.
Reverse voltage

Package Dimensions

Unit: mm

